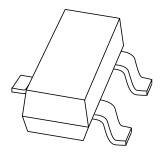
## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



## BCW71; BCW72 NPN general purpose transistors

Product data sheet Supersedes data of 1997 Mar 06 1999 Apr 19



NXP Semiconductors Product data sheet

## **NPN** general purpose transistors

**BCW71; BCW72** 

#### **FEATURES**

- Low current (100 mA)
- Low voltage (45 V)
- · Low noise.

#### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

NPN transistor in a SOT23 plastic package. PNP complements: BCW69 and BCW70.

#### **MARKING**

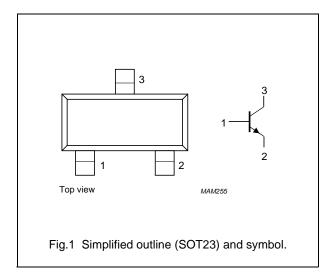
| TYPE NUMBER | MARKING CODE(1) |
|-------------|-----------------|
| BCW71       | K1*             |
| BCW72       | K2*             |

#### Note

\* = p : Made in Hong Kong.
 \* = t : Made in Malaysia.

#### **PINNING**

| PIN | DESCRIPTION |  |
|-----|-------------|--|
| 1   | base        |  |
| 2   | emitter     |  |
| 3   | collector   |  |



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL           | PARAMETER                     | CONDITIONS                       | MIN. | MAX. | UNIT |
|------------------|-------------------------------|----------------------------------|------|------|------|
| V <sub>CBO</sub> | collector-base voltage        | open emitter                     | _    | 50   | V    |
| $V_{CEO}$        | collector-emitter voltage     | open base; I <sub>C</sub> = 2 mA | _    | 45   | V    |
| $V_{EBO}$        | emitter-base voltage          | open collector                   | _    | 5    | V    |
| I <sub>C</sub>   | collector current (DC)        |                                  | _    | 100  | mA   |
| I <sub>CM</sub>  | peak collector current        |                                  | _    | 200  | mA   |
| $I_{BM}$         | peak base current             |                                  | _    | 200  | mA   |
| P <sub>tot</sub> | total power dissipation       | T <sub>amb</sub> ≤ 25 °C         | _    | 250  | mW   |
| T <sub>stg</sub> | storage temperature           |                                  | -65  | +150 | °C   |
| Tj               | junction temperature          |                                  | _    | 150  | °C   |
| T <sub>amb</sub> | operating ambient temperature |                                  | -65  | +150 | °C   |

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NXP Semiconductors Product data sheet

## NPN general purpose transistors

BCW71; BCW72

#### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                                   | CONDITIONS | VALUE | UNIT |  |
|---------------------|---|------------|-------|------|--|
| R <sub>th j-a</sub> | thermal resistance from junction to ambient | note 1     | 500   | K/W  |  |

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### **CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

| SYMBOL             | PARAMETER                       | CONDITIONS  | MIN. | TYP. | MAX. | UNIT |
|--------------------|---------------------------------|---|------|------|------|------|
| I <sub>CBO</sub>   | collector cut-off current       | I <sub>E</sub> = 0; V <sub>CB</sub> = 20 V  | _    | _    | 100  | nA   |
|                    |                                 | $I_E = 0$ ; $V_{CB} = 20 \text{ V}$ ; $T_j = 100 ^{\circ}\text{C}$                        | _    | -    | 10   | μΑ   |
| I <sub>EBO</sub>   | emitter cut-off current         | $I_C = 0; V_{EB} = 5 \text{ V}$   | -    | _    | 100  | μΑ   |
| h <sub>FE</sub>    | DC current gain                 | $I_C = 10 \mu A; V_{CE} = 5 V$  |      |      |      |      |
|                    | BCW71                           |   | _    | 90   | _    |      |
|                    | BCW72                           |   | _    | 150  | _    |      |
|                    | DC current gain                 | $I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$  |      |      |      |      |
|                    | BCW71                           |   | 110  | -    | 220  |      |
|                    | BCW72                           |   | 200  | _    | 450  |      |
| V <sub>CEsat</sub> | collector-emitter saturation    | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$   | _    | 120  | 250  | mV   |
|                    | voltage                         | $I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}$   | -    | 210  | _    | mV   |
| $V_{BEsat}$        | base-emitter saturation voltage | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$   | -    | 750  | _    | mV   |
|                    |                                 | $I_C = 50 \text{ mA}; I_B = 2.5 \text{ mA}$   | _    | 850  | _    | mV   |
| $V_{BE}$           | base-emitter voltage            | $I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$  | 550  | -    | 700  | mV   |
| C <sub>c</sub>     | collector capacitance           | $I_E = I_e = 0$ ; $V_{CB} = 10 \text{ V}$ ; $f = 1 \text{ MHz}$                           | _    | 2.5  | _    | pF   |
| f <sub>T</sub>     | transition frequency            | $I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz}$                          | 100  | _    | _    | MHz  |
| F                  | noise figure                    | $I_C = 200 \ \mu A; \ V_{CE} = 5 \ V; \ R_S = 2 \ k\Omega;$ $f = 1 \ kHz; \ B = 200 \ Hz$ | _    | _    | 10   | dB   |

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**NXP Semiconductors** Product data sheet

## NPN general purpose transistors

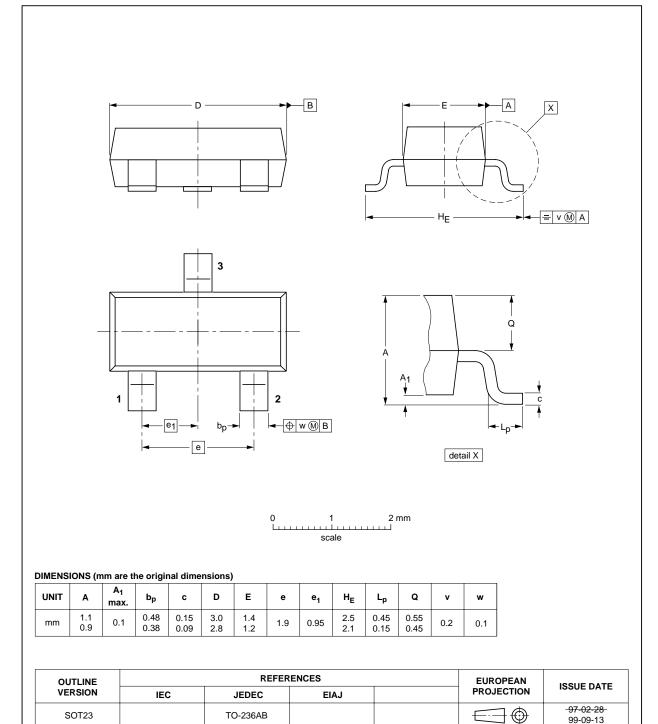
**BCW71**; **BCW72** 

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

SOT23

99-09-13



TO-236AB

SOT23

NXP Semiconductors Product data sheet

### NPN general purpose transistors

**BCW71**; **BCW72** 

#### **DATA SHEET STATUS**

| DOCUMENT<br>STATUS <sup>(1)</sup> | PRODUCT<br>STATUS <sup>(2)</sup> | DEFINITION  |
|-----------------------------------|----------------------------------|---|
| Objective data sheet              | Development                      | This document contains data from the objective specification for product development. |
| Preliminary data sheet            | Qualification                    | This document contains data from the preliminary specification.                       |
| Product data sheet                | Production                       | This document contains the product specification.                                     |

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#### **Contact information**

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